

INFORMATION DISCLOSURE  
CITATION

ATTY. DOCKET NO.

SERIAL NO.

160-356

09/809,038

APPLICANT

NAKAMURA et al.

FILING DATE

GROUP

March 16, 2001

2814

## U.S. PATENT DOCUMENTS

INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
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	Khan et al., Reflective Filters Based on Single-Crystal GaN/AlxGal-xN Multilayers Deposited Using Low-Pressure Metalorganic Chemical Vapor Deposition, Appl. Phys. Lett., Vol. 59, No. 12
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Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to application.

Form PTO-FB-A820 (Also PTO-1449)

### INFORMATION DISCLOSURE CITATION

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**160-356**

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**TBA**

(Use several sheets if necessary)

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\*Examiner

Date Considered

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